CD74HCT574-Q1 HIGH-SPEED CMOS LOGIC OCTAL D-TYPE FLIP-FLOP 3-STATE, POSITIVE-EDGE TRIGGERED

SCLS570A - FEBRUARY 2004 - REVISED APRIL 2008

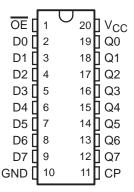
- Qualified for Automotive Applications
- Buffered Inputs
- Common 3-State Output-Enable Control
- 3-State Outputs
- Bus-Line Driving Capability
- Typical Propagation Delay (Clock to Q): 15 ns at V_{CC} = 5 V, C_L = 15 pF, T_A = 25°C
- Fanout (Over Temperature Range)
 - Standard Outputs ... 10 LSTTL Loads
 - Bus Driver Outputs ... 15 LSTTL Loads
- Balanced Propagation Delay and Transition Times

description/ordering information

The CD74HCT574 is an octal D-type flip-flop with 3-state outputs and the capability to drive 15 LSTTL loads. The eight edge-triggered flip-flops enter data into their registers on the low-to-high transition of the clock (CP). The output enable (\overline{OE}) controls the 3-state outputs and is independent of the register operation. When \overline{OE} is high, the outputs are in the high-impedance state.

- Significant Power Reduction Compared to LSTTL Logic ICs
- V_{CC} Voltage = 4.5 V to 5.5 V
- Direct LSTTL Input Logic Compatibility,
 V_{IL} = 0.8 V (Max), V_{IH} = 2 V (Min)
- CMOS Input Compatibility, $I_I \le 1 \mu A$ at V_{OL} , V_{OH}

M OR PW PACKAGE (TOP VIEW)



ORDERING INFORMATION[†]

TA	PACK	AGE‡	ORDERABLE PART NUMBER	TOP-SIDE MARKING
4000 to 40500	SOIC - M	Tape and reel	CD74HCT574QM96Q1	HCT574Q
-40°C to 125°C	TSSOP - PW	Tape and reel	CD74HCT574QPWRQ1	HCT574Q

[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



[‡] Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.

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FUNCTION TABLE

	INPUTS								
OE	CP	D	Q						
L	1	Н	Н						
L	1	L	L						
L	L	Χ	Q ₀						
Н	X	Χ	Z						

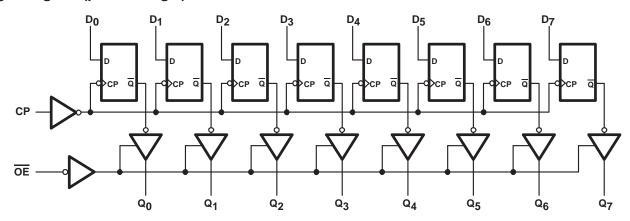
NOTE: H = High voltage level (steady state) L = Low voltage level (steady state)

X = Don't care

 \uparrow = Transition from low to high level Q_0 = Level before the indicated steady-state conditions were established

Z = High-impedance state

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} (see Note 1)	0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$)	±20 mA
Output clamp current, I_{OK} ($V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$)	±20 mA
Drain current per output, I_O ($V_O > -0.5 \text{ V}$ or $V_O < V_{CC} + 0.5 \text{ V}$)	±35 mA
Output source or sink current per output, I_O ($V_O > -0.5$ V or $V_O < V_{CC} + 0.5$ V)	±25 mA
Continuous current through V _{CC} or GND, I _{CC}	±50 mA
Package thermal impedance, θ _{JA} (see Note 2): M package	58°C/W
PW package	69°C/W
Maximum junction temperature, T _J	150°C
Lead temperature (during soldering):	
At distance 1/16 \pm 1/32 inch (1,59 \pm 0,79 mm) from case for 10 s max	300°C
Storage temperature range, T _{stq}	. -65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages referenced to GND unless otherwise specified.

recommended operating conditions (see Note 3)

		М	IN	MAX	UNIT
Vcc	Supply voltage	4	.5	5.5	V
VIH	High-level input voltage $V_{CC} = 4.5 \text{ V}$ to	5.5 V	2		V
VIL	Low-level input voltage $V_{CC} = 4.5 \text{ V}$ to	5.5 V		0.8	V
VI	Input voltage		0	VCC	V
VO	Output voltage		0	VCC	V
	V _{CC} = 2 V		0	1000	
t _t	Input transition (rise and fall) time $V_{CC} = 4.5 \text{ V}$		0	500	ns
	V _{CC} = 6 V		0	400	
TA	Operating free-air temperature	_	40	125	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



^{2.} The package thermal impedance is calculated in accordance with JESD 51-7.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	NDITIONS	lo (mA)	IO (mA) V _{CC} T _A = 25°C			;	T _A = -	UNIT	
			(IIIA)		MIN	TYP	MAX	MIN	MAX	
.,,	V VV	CMOS loads	-0.02	4.5 V	4.4			4.4		.,
VOH	$V_I = V_{IH}$ or V_{IL}	TTL loads	-6	4.5 V	3.98			3.7		V
.,,	V VV	CMOS loads	0.02	4.5 V			0.1		0.1 V	.,
V _{OL}	VI = VIH or VIL	TTL loads	6	4.5 V			0.26		0.4	V
lį	$V_I = V_{CC}$ or GND		0	5.5 V			±0.1		±1	μΑ
loz	$V_I = V_{IL} \text{ or } V_{IH},$	$V_O = V_{CC}$ or GND		6 V			±0.5		±10	μΑ
ICC	$V_I = V_{CC}$ or GND		0	5.5 V			8		160	μΑ
ΔlCC	$V_{I} = V_{CC} - 2.1 V,$	See Note 4		4.5 V to 5.5 V		100	360		490	μΑ
C _{IN}	C _L = 50 pF						10		10	pF
COUT	3-state	_					20		20	pF

NOTE 4: For dual-supply systems, theoretical worst-case (V_I = 2.4 V, V_{CC} = 5.5 V) specification is 1.8 mA.

HCT input loading

TYPE	INPUT	UNIT LOADS†
	D0-D7	0.4
'574	CP	0.75
	ŌĒ	0.6

 $^{^{\}dagger}$ Unit load is ΔI_{CC} limit specified in electrical characteristics table, e.g., 360 μA max at 25°C.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

	PARAMETER	Vcc	T _A = 2	25°C	T _A = -	UNIT	
			MIN	MAX	MIN	MAX	
f _{max}	Maximum clock frequency	4.5 V	30		20		MHz
t _W	Clock pulse duration	4.5 V	16		24		ns
t _{su}	Setup time, data before clock↑	4.5 V	12		18		ns
th	Hold time, data after clock ↑	4.5 V	5		5		ns

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switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	LOAD	ν _{CC}	T _A = 25°C			T _A = -	UNIT	
	(INPUT)	(OUTPUT)	CAPACITANCE		MIN	TYP	MAX	MIN	MAX	
	CD.	_	C _L = 50 pF	4.5 V			33		50	
^t pd	СР	Q	C _L = 15 pF	5 V		15				ns
4	t _{dis} OE	_	C _L = 50 pF	4.5 V			28		42	
^t dis	OE	Q	C _L = 15 pF	5 V		11				ns
	ŌĒ	C _L = 50 pF 4.5 V		30		45				
^t en	OE	Q	C _L = 15 pF	5 V		12				ns
t _t		Q	C _L = 50 pF	4.5 V			12	·	18	ns
f _{max}	СР		C _L = 15 pF	5 V		60		·		MHz

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$, input t_r , $t_f = 6 \text{ ns}$

	PARAMETER	TYP	UNIT
C _{pd}	Power dissipation capacitance (see Note 5)	47	pF

NOTE 5: C_{pd} is used to determine the dynamic power consumption (P_D), per package.

 $P_D = (C_{PD} \times V_{CC}^2 \times f_I) + \Sigma (C_L \times V_{CC}^2 \times f_O)$

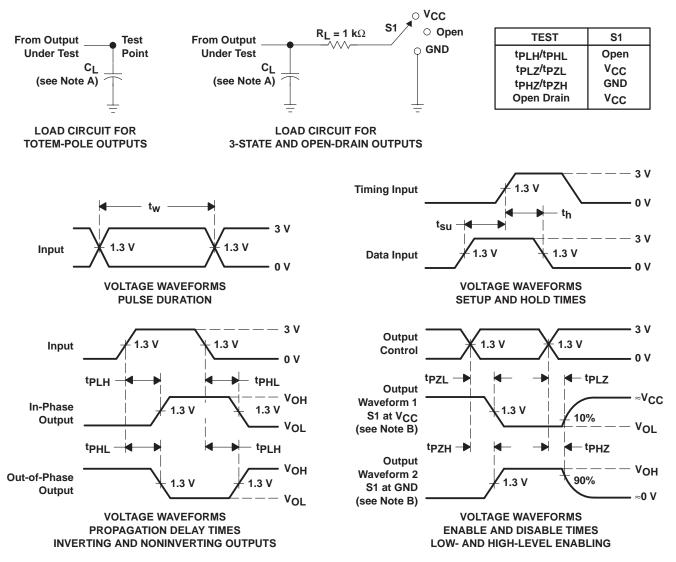
f_I = input frequency

f_O = output frequency

C_L = output load capacitance

V_{CC} = supply voltage

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 6 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.
- F. tpLH and tpHL are the same as tpd.
- G. tpLz and tpHz are the same as tdis.
- H. tpzH and tpzL are the same as ten.

Figure 1. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
CD74HCT574QM96G4Q1	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HCT574Q1
CD74HCT574QM96G4Q1.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HCT574Q1
CD74HCT574QPWRG4Q1	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HCT574Q1
CD74HCT574QPWRG4Q1.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HCT574Q1

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD74HCT574-Q1:

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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● Enhanced Product : CD74HCT574-EP

• Military : CD54HCT574

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

● Enhanced Product - Supports Defense, Aerospace and Medical Applications

• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

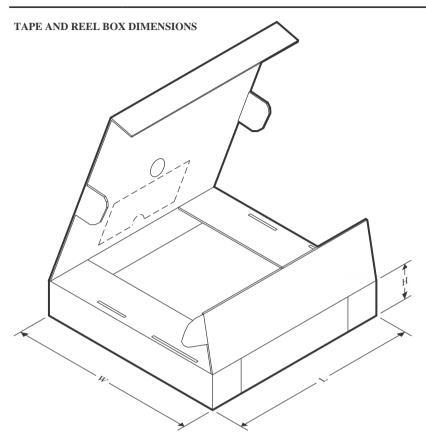


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HCT574QM96G4Q1	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74HCT574QPWRG4Q1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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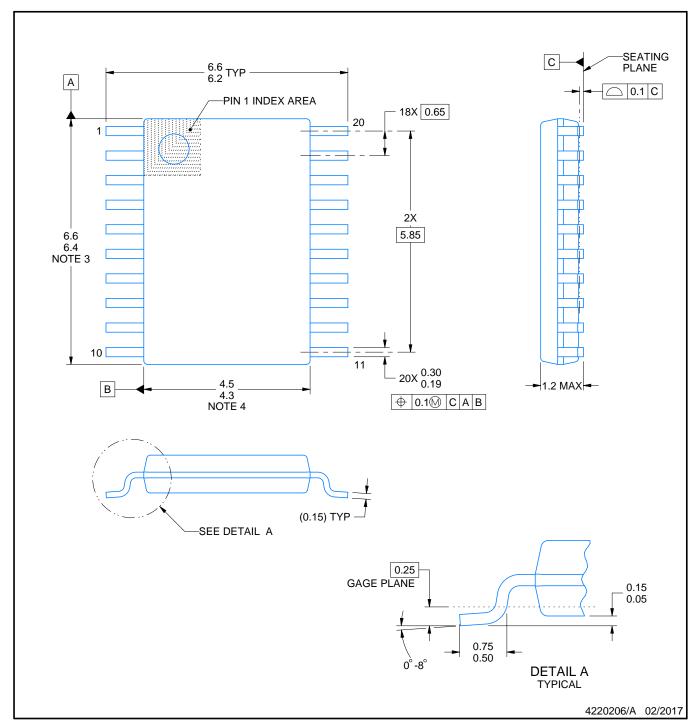


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HCT574QM96G4Q1	SOIC	DW	20	2000	356.0	356.0	45.0
CD74HCT574QPWRG4Q1	TSSOP	PW	20	2000	353.0	353.0	32.0



SMALL OUTLINE PACKAGE



NOTES:

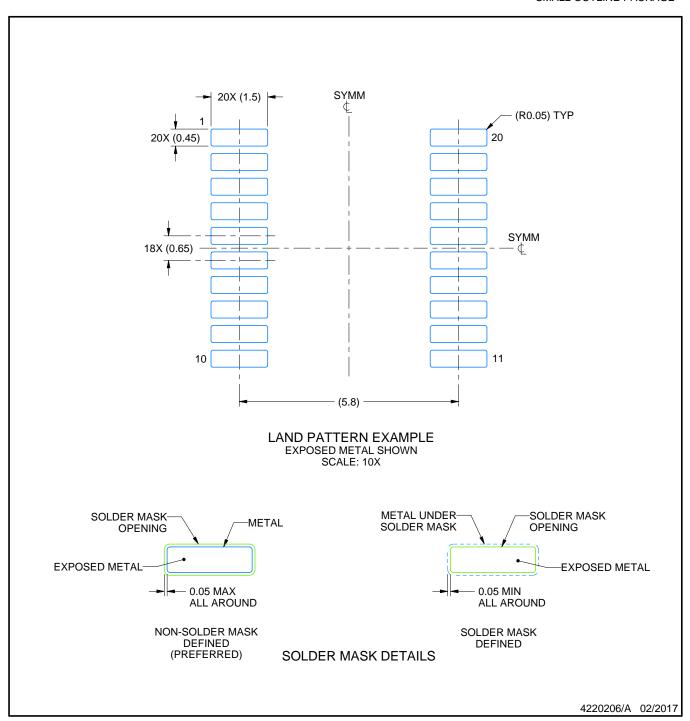
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



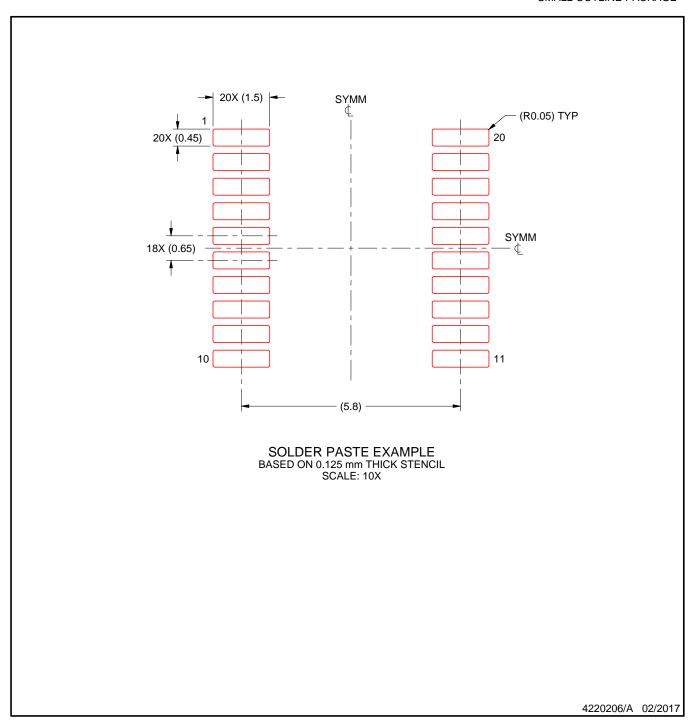
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



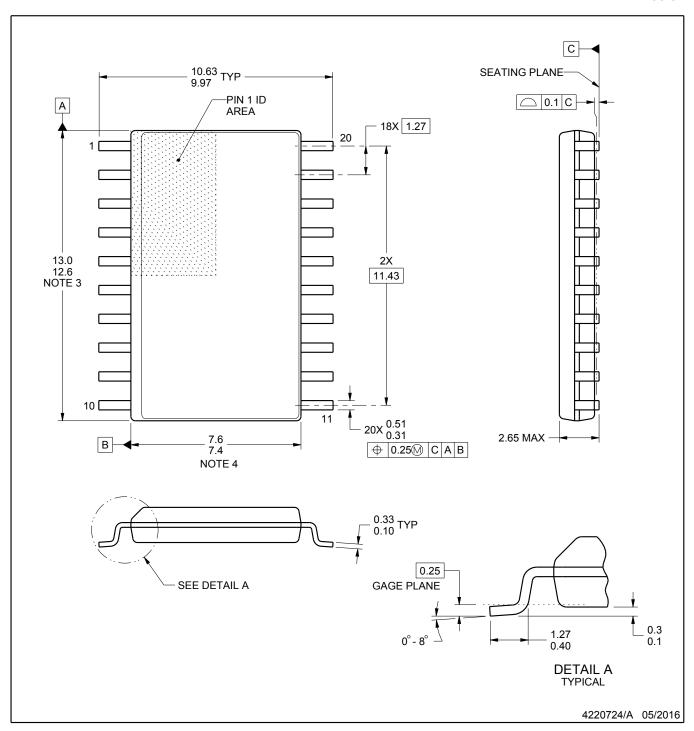
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SOIC



NOTES:

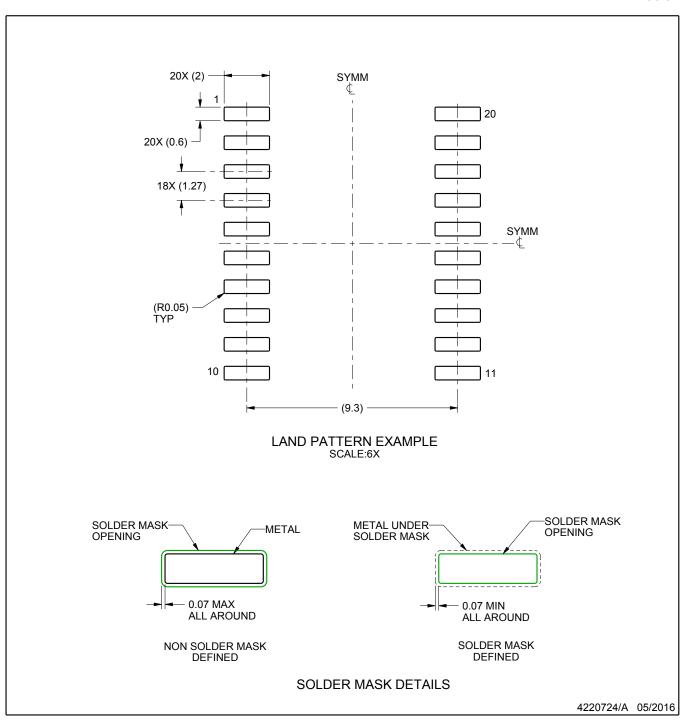
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
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- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



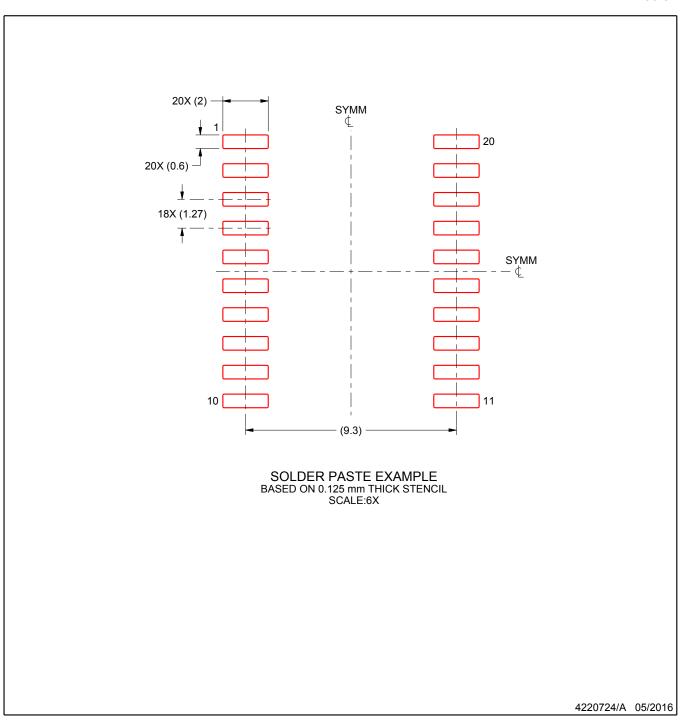
NOTES: (continued)

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SOIC



NOTES: (continued)

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- 9. Board assembly site may have different recommendations for stencil design.



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